

BC807-40QBZ Datasheet



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DiGi Electronics Part Number BC807-40QBZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC807-40QBZ

Description TRANS 45V 0.5A DFN1110D-3

Detailed Description Bipolar (BJT) Transistor 45 V 500 mA 80MHz 350 mW

Surface Mount, Wettable Flank DFN1110D-3



Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC807-40QBZ	Nexperia USA Inc.
Series:	Product Status:
	Active
Current - Collector (Ic) (Max):	Voltage - Collector Emitter Breakdown (Max):
500 mA	45 V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
700mV @ 50mA, 500mA	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce:	Power - Max:
250 @ 100mA, 1V	350 mW
Frequency - Transition:	Operating Temperature:
80MHz	150°C (TJ)
Mounting Type:	Package / Case:
Surface Mount, Wettable Flank	3-XDFN Exposed Pad
Supplier Device Package:	
DFN1110D-3	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

1. General description

PNP general-purpose transistor in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	Package	NPN complement		
	Name	JEDEC	Version	
BC807-16QB	DFN1110D-3	MO340-BA	SOT8015	BC817-16QB
BC807-25QB				BC817-25QB
BC807-40QB				BC817-40QB

2. Features and benefits

- · High power dissipation capability
- High current
- Three current gain selections
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- · Smaller footprint compared to conventional leaded SMD packages
- Low package height of 0.5 mm

3. Applications

- · General-purpose switching and amplification
- Space restricted applications

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	-45	V
I _C	collector current	T _{amb} = 25 °C		-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	-	-1	Α	
h _{FE}	DC current gain						•
	BC807-16QB	V _{CE} = -1 V; I _C = -100 mA T _{amb} = 25 °C	[1]	100	-	250	
	BC807-25QB		[1]	160	-	400	
	BC807-40QB		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		C
2	E	emitter		В—
3	С	collector	DFN1110D-3 (SOT8015)	E sym132

6. Ordering information

Table 4. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
BC807-16QB	DFN1110D-3	· _ · _ ·	SOT8015 (MO340-				
BC807-25QB		package; no leads; 3 terminals; body: 1.1 x 1.0 x 0.5 mm	BA)				
BC807-40QB							

7. Marking

Table 5. Marking

Type number	Marking code
BC807-16QB	A8
BC807-25QB	A9
BC807-40QB	B2

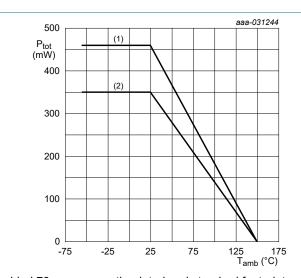
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C		-50	V
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	-5	V
Ic	collector current	T _{amb} = 25 °C	T _{amb} = 25 °C			mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb}	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb}	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW
			[2]	-	460	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint.



- (1) FR4 PCB; single-sided 70 μm copper, tin-plated and standard footprint
- (2) FR4 PCB; single-sided 35 µm copper, tin-plated and standard footprint

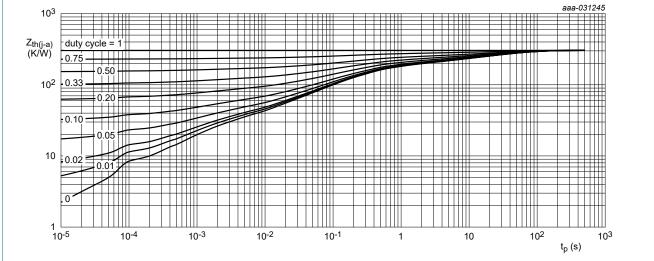
Fig. 1. Power derating curves for SOT8015

9. Thermal characteristics

Table 7. Thermal characteristics

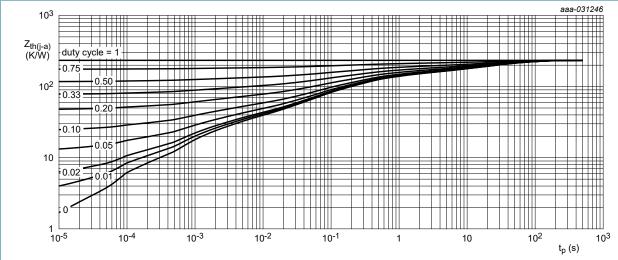
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air;	[1]	-	-	358	K/W
		T _{amb} = 25 °C	[2]	-	-	272	K/W

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided 35µm copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided 70µm copper, tin-plated and standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

BC807QB series

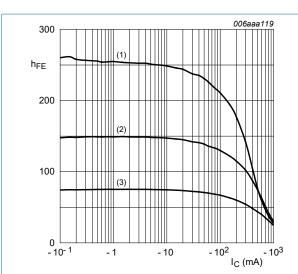
45 V, 500 mA PNP general-purpose transistors

10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C		-50	-		V
V _{(BR)CEO}	collector-emitter breakdown voltage	I_C = -10 mA; I_E = 0 A; T_{amb} = 25 °C		-45	-		V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_E = -100 \ \mu A; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$		-5	-		V
I _{CBO}	collector-base	V _{CB} = -20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	cut-off current	V _{CB} = -20 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain			'	'	'	
BC807-16QB BC807-25QB	BC807-16QB	V _{CE} = -1 V; I _C = -100 mA; T _{amb} = 25 °C	100	-	250		
	BC807-25QB		[1]	160	-	400	
	BC807-40QB		[1]	250	-	600	
		V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = -500 mA; I_{B} = -50 mA; T_{amb} = 25 °C	[1]	-	-	-700	mV
V_{BE}	base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1] [2]	-	-	-1.2	V
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C		80	-	-	MHz
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = I_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	5	-	pF

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu\text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



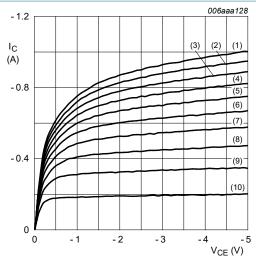
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 4. BC807-16QB: DC current gain as a function of collector current; typical values



(1)
$$I_B = -16.0 \text{ mA}$$

(2)
$$I_B = -14.4 \text{ mA}$$

(3)
$$I_B = -12.8 \text{ mA}$$

$$(4) I_B = -11.2 \text{ mA}$$

$$(5) I_B = -9.6 \text{ mA}$$

(6)
$$I_B = -8.0 \text{ mA}$$

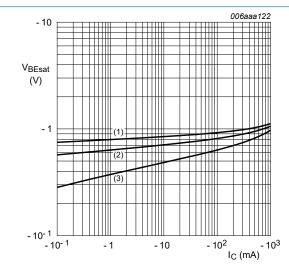
(7)
$$I_B = -6.4 \text{ mA}$$

(8)
$$I_B = -4.8 \text{ mA}$$

(9)
$$I_B = -3.2 \text{ mA}$$

$$(10) I_B = -1.6 mA$$

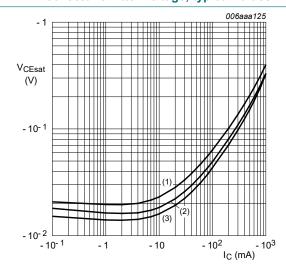
Fig. 5. BC807-16QB: Collector current as a function of collector-emitter voltage; typical values



(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

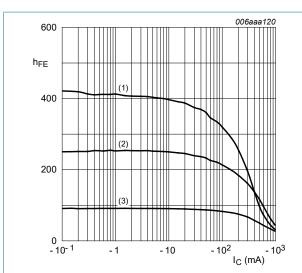
Fig. 6. BC807-16QB: Base-emitter saturation voltage as a function of collector current; typical values



(2)
$$T_{amb} = 25 \,^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 7. BC807-16QB: Collector-emitter saturation voltage as a function of collector current; typical values



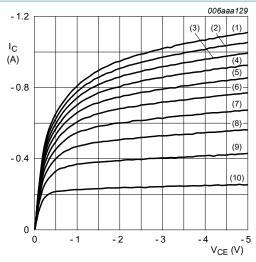
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 8. BC807-25QB: DC current gain as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -13.0 \text{ mA}$$

(2)
$$I_B = -11.7 \text{ mA}$$

(3)
$$I_B = -10.4 \text{ mA}$$

$$(4) I_B = -9.1 \text{ mA}$$

$$(5) I_B = -7.8 \text{ mA}$$

(6)
$$I_B = -6.5 \text{ mA}$$

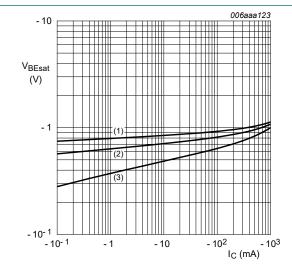
(7)
$$I_B = -5.2 \text{ mA}$$

(8)
$$I_B = -3.9 \text{ mA}$$

(9)
$$I_B = -2.6 \text{ mA}$$

$$(10) I_B = -1.3 \text{ mA}$$

Fig. 9. BC807-25QB: Collector current as a function of collector-emitter voltage; typical values

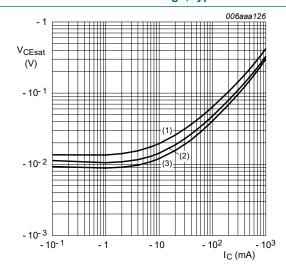


(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

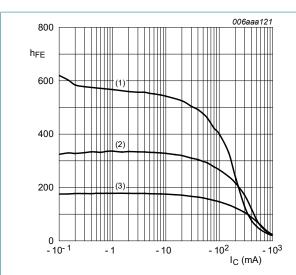
Fig. 10. BC807-25QB: Base-emitter saturation voltage as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 11. BC807-25QB: Collector-emitter saturation voltage as a function of collector current; typical values



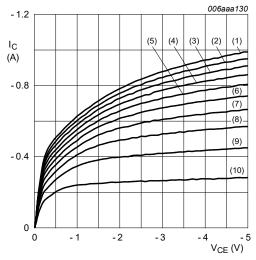
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 12. BC807-40QB: DC current gain as a function of collector current; typical values



(1)
$$I_B = -12.0 \text{ mA}$$

$$(2) I_B = -10.8 \text{ mA}$$

(3)
$$I_B = -9.6 \text{ mA}$$

$$(4) I_B = -8.4 \text{ mA}$$

$$(5) I_B = -7.2 \text{ mA}$$

(6)
$$I_B = -6.0 \text{ mA}$$

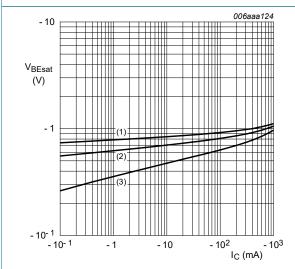
$$(7) I_B = -4.8 \text{ mA}$$

(8)
$$I_B = -3.6 \text{ mA}$$

(9)
$$I_B = -2.4 \text{ mA}$$

$$(10) I_B = -1.2 mA$$

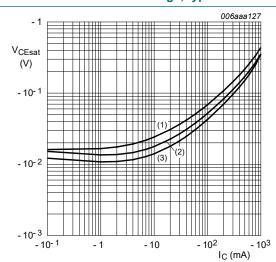
Fig. 13. BC807-40QB: Collector current as a function of collector-emitter voltage; typical values



(1)
$$T_{amb} = -55$$
 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

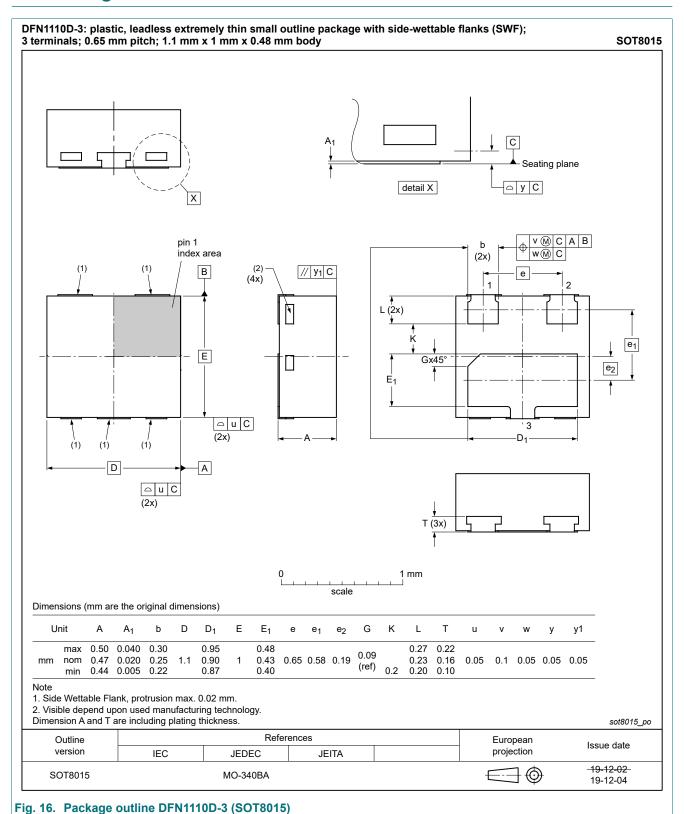
Fig. 14. BC807-40QB: Base-emitter saturation voltage as a function of collector current; typical values



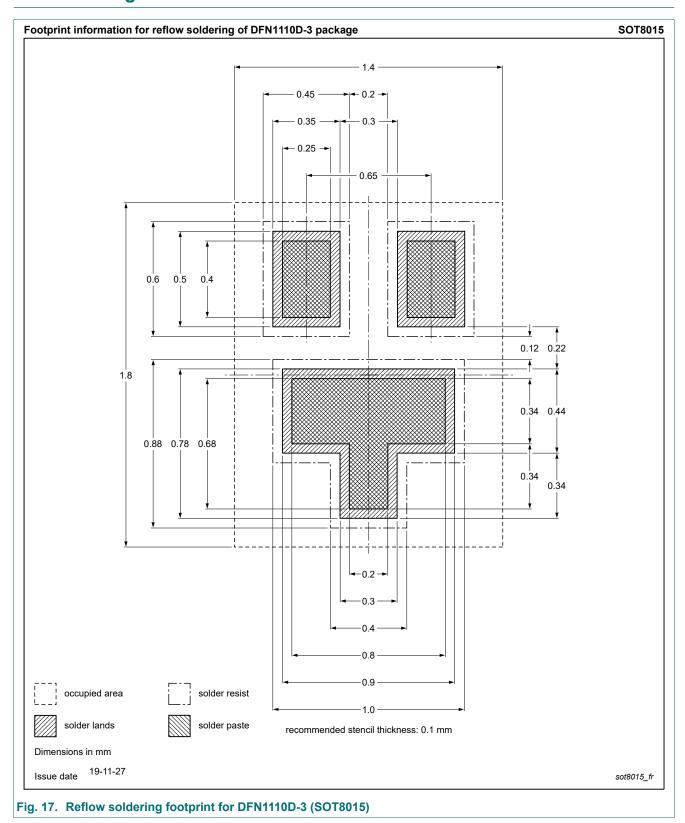
(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 15. BC807-40QB: Collector-emitter saturation voltage as a function of collector current; typical values

11. Package outline



12. Soldering



BC807QB series

45 V, 500 mA PNP general-purpose transistors

13. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BC807QB_SER v.2	20230701	Product data sheet	-	BC807QB_SER v.1		
Modifications:	 Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 					
BC807QB_SER v.1	20201210	Product data sheet	-	-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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BC807QB series

45 V, 500 mA PNP general-purpose transistors

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